

-100V P-Channel Enhancement Mode MOSFET

Description

The SX3P10S uses advanced trench technology to provide excellent RDS(ON), low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

V_{DS} = -100V I_D =-3A

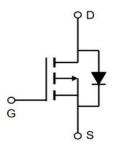
 $R_{DS(ON)} < 600 m\Omega$ @ $V_{GS}=10V$

Application

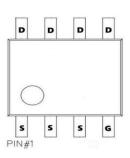
Battery protection

Load switch

Uninterruptible power supply







Absolute Maximum Ratings (Tc=25℃unless otherwise noted

Symbol	Parameter	Rating	Units
Vos	Drain-Source Voltage	Drain-Source Voltage -100	
Vgs	Gate-Source Voltage	±20	V
lo@Ta=25°C	Continuous Drain Current, V _{GS} @ -10V ¹ -3		А
lo@Ta=70°C	Continuous Drain Current, V _{GS} @ -10V ¹	s Drain Current, V _{GS} @ -10V ¹ -1.7	
Ірм	Pulsed Drain Current ²	-9.8	А
P o@T a=25℃	Total Power Dissipation ³	1	W
Тѕтс	Storage Temperature Range	-55 to 150	$^{\circ}$
TJ	Operating Junction Temperature Range	-55 to 150	$^{\circ}$
Reja	Thermal Resistance Junction-ambient ¹	85	°C/W
Rejc	Thermal Resistance Junction-Case ¹	80 °C/W	





Electrical Characteristics (T_A=25 [°]Cunless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	VGS=0V , ID=-250uA	-100	-111		V
△BVDSS/△T J	BVDSS Temperature Coefficient	Reference to 25℃, ID=-1mA		-0.0624		V/℃
DDQ(QNI)	0	VGS=-10V , ID=-0.8A		450	600	mΩ
RDS(ON)	Static Drain-Source On-Resistance2	VGS=-4.5V , ID=-0.4A		560	700	mΩ
VGS(th)	Gate Threshold Voltage	\\CC-\\DC \D = 250\	-1.0		-2.5	V
△VGS(th)	VGS(th) Temperature Coefficient	VGS=VDS , ID =-250uA		4.5		mV/℃
IDSS	Drain-Source Leakage Current	VDS=-80V , VGS=0V ,TJ=25℃			10	uA
פפטו	Drain-Source Leakage Current	VDS=-80V , VGS=0V ,TJ=55℃			100	uA
IGSS	Gate-Source Leakage Current	VGS=±20V , VDS=0V			±100	nA
gfs	Forward Transconductance	VDS=-5V , ID=-0.8A		3		S
Rg	Gate Resistance	VDS=0V , VGS=0V , f=1MHz		16	32	Ω
Qg	Total Gate Charge (-4.5V)			4.5		nC
Qgs	Gate-Source Charge	VDS=-15V , VGS=-4.5V , ID=-0.5A		1.14		nC
Qgd	Gate-Drain Charge	1.5 6.6.1		1.5		nC
Td(on)	Turn-On Delay Time			13.6		ns
Tr	Rise Time	VDD=-50V , VGS=-10V ,		6.8		ns
Td(off)	Turn-Off Delay Time	RG=3.3Ω ID=-0.5A		34		ns
Tf	Fall Time			3		ns
Ciss	Input Capacitance			553		pF
Coss	Output Capacitance	VDS=-15V , VGS=0V , f=1MHz		29		pF
Crss	Reverse Transfer Capacitance			20		pF
IS	Continuous Source Current1,4	VG=VD=0V , Force Current			-0.9	Α
ISM	Pulsed Source Current2,4				-1.8	Α
VSD	Diode Forward Voltage2	VGS=0V , IS=-1A , TJ=25℃			-1.2	V

Note:

- 1. The data tested by surface mounted on a 1 inch2 FR-4 board with 2OZ copper.
- 2 . The data tested by pulsed , pulse width $\leq 300 \text{us}$, duty cycle $\leq 2\%$
- 3 . The power dissipation is limited by 150°C junction temperature
- 4. The data is theoretically the same as ID and IDM, in real applications, should be limited by total power dissipation.

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Typical Characteristics

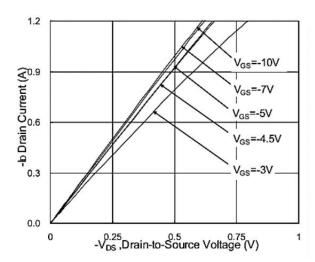


Fig.1 Typical Output Characteristics

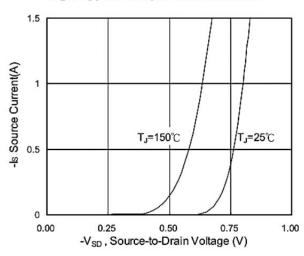


Fig.3 Forward Characteristics Of Reverse

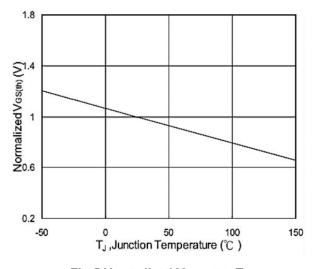


Fig.5 Normalized V_{GS(th)} vs. T_J

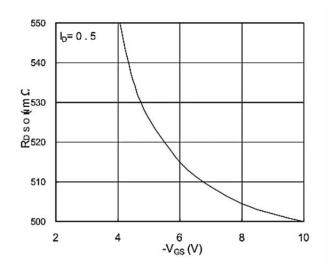


Fig.2 On-Resistance vs. Gate-Source

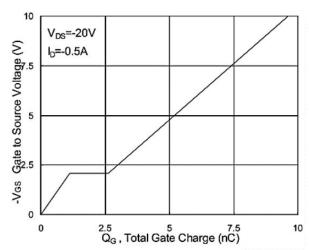


Fig.4 Gate-Charge Characteristics

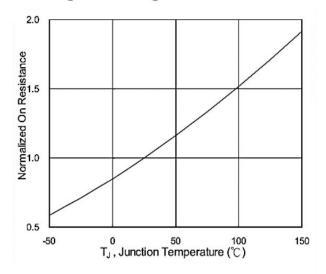
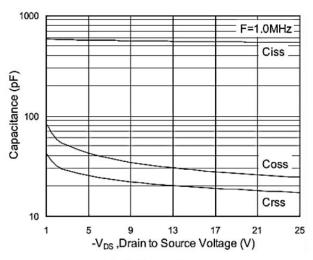


Fig.6 Normalized RDSON vs. TJ



Typical Characteristics



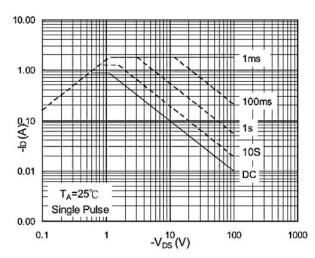


Fig.7 Capacitance

Fig.8 Safe Operating Area

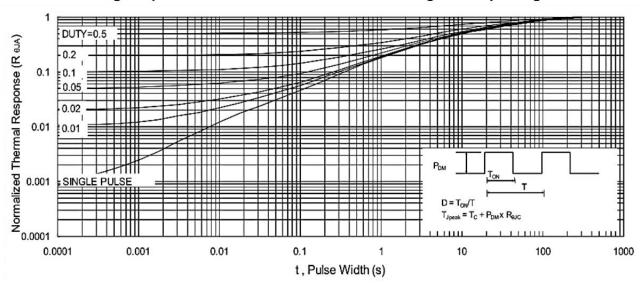
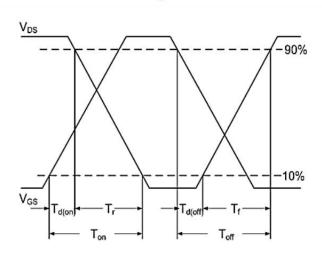


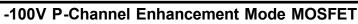
Fig.9 Normalized Maximum Transient Thermal Impedance



-V_Gs Qg 4.5V Qgs Qgd Charge

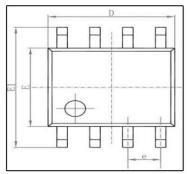
Fig.10 Switching Time Waveform

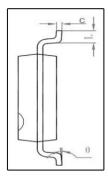
Fig.11 Gate Charge Waveform

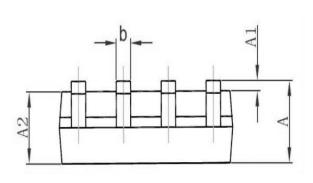




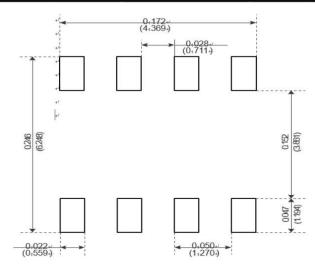
Package Mechanical Data-SOP-8







Cl I	Dimensions In	n Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1. 350	1. 750	0. 053	0.069
A1	0. 100	0. 250	0.004	0. 010
A2	1. 350	1. 550	0. 053	0.061
b	0. 330	0. 510	0. 013	0. 020
С	0. 170	0. 250	0.006	0. 010
D	4. 700	5. 100	0. 185	0. 200
E	3. 800	4. 000	0. 150	0. 157
E1	5. 800	6. 200	0. 228	0. 244
е	1. 270 (BSC)		0. 050 (BSC)	
L	0. 400	1. 270	0. 016	0.050
θ	0°	8°	0°	8°



Recommended Minimum Pads

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)		
TAPING	SOP-8		3000		

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